

Type 2N3057A
Geometry 4500
Polarity NPN
Qual Level: JAN - JANS

Generic Part Number: 2N3057A

REF: MIL-PRF-19500/391

Request Quotation

Features:

- General-purpose transistor for switching and amplifier applicatons.
- Housed in a TO-46 case.
- Also available in chip form using the 4500 chip geometry.
- The Min and Max limits shown are per MIL-PRF-19500/391 which Semicoa meets in all cases.
- · Radiation Graphs available.



TO-46

Maximum Ratings

 $T_C = 25^{\circ}C$ unless otherwise specified

Rating	Symbol	Rating	Unit	
Collector-Emitter Voltage	V_{CEO}	80	V	
Collector-Base Voltage	V_{CBO}	140	V	
Emitter-Base Voltage	V_{EBO}	7.0	V	
Collector Current, Continuous	I _C	1.0	mA	
Operating Junction Temperature	T_J	-55 to +175	°C	
Storage Temperature	T _{STG}	-55 to +175	°C	



Electrical Characteristics

 $T_C = 25^{\circ}C$ unless otherwise specified

OFF Characteristics	Symbol	Min	Max	Unit
Collector-Base Breakdown Voltage $I_C = 100 \mu A$	V _{(BR)CBO}	140		V
Collector-Emitter Breakdown Voltage $I_C = 30 \text{ mA}$	V _{(BR)CEO}	80		V
Emitter-Base Breakdown Voltage $I_E = 100 \mu A$	V _{(BR)EBO}	7.0		V
Collector-Emitter Cutoff Current V _{CE} = 90 V	I _{CES}		10	nA
Emitter-Base Cutoff Current $V_{EB} = 5 \text{ V}$	I _{EBO}		10	nA

ON Characteristics	Symbol	Min	Max	Unit
DC Current Gain				
$I_C = 150 \text{ mA}, V_{CE} = 10 \text{ V}$	h _{FE1}	100	300	
$I_C = 0.1 \text{ mA}, V_{CE} = 10 \text{ V}$	h _{FE2}	50	200	
$I_C = 10 \text{ mA}, V_{CE} = 10 \text{ V (pulse test)}$	h _{FE3}	90		
$I_C = 500 \text{ mA}, V_{CE} = 10 \text{ V (pulse test)}$	h _{FE4}	50	200	
$I_C = 1 \text{ A}, V_{CE} = 10 \text{ V} \text{ (pulse test)}$	h _{FE5}	15		
Collector-Emitter Saturation Voltage				
$I_C = 150 \text{ mA}, I_B = 15 \text{ mA} \text{ (pulse test)}$	$V_{CE(sat)1}$		0.2	V dc
$I_C = 500 \text{ mA}, I_B = 50 \text{ mA} \text{ (pulse test)}$	$V_{CE(sat)2}$		0.5	V dc
Base-Emitter Saturation Voltage				
I_C = 150 mA, I_B = 15 mA (pulse test)	$V_{BE(sat)}$		1.1	V dc

Small Signal Characteristics	Symbol	Min	Max	Unit
Short Circuit Forward Current Transfer Ratio $I_C = 1 \text{ mA}, V_{CE} = 5 \text{ V}, f = 1 \text{ kHz}$	AC h _{FE}	80	400	
Magnitude of Common Emitter Short Circuit Forward Current Transfer Ratio $V_{CE} = 10 \text{ V}, I_{C} = 50 \text{ mA}, f = 200 \text{ MHz}$	h _{FE}	5.0	20	
Open Circuit Output Capacitance V _{CB} = 10 V, I _E = 0, 100 kHz < f < 1 MHz	C _{OBO}		12	pF
Input Capacitance, Output Open Circuited V _{EB} = 2.0 V, I _C = 0, 100 kHz < f < 1 MHz	C _{IBO}		60	pF
Collecor-Base Time Constant V _{CE} = 10 V, I _C = 10 mA, f = 79.8 MHz	$r_{b'}C_C$		400	ps
Noise Figure $V_{CE} = 10 \text{ V}, I_{C} = 100 \mu\text{A}, R_{g} = 1 \text{ kOhm}$	NF		4	dB

Switching Characteristics	Symbol	Min	Max	Unit
Pulse Response 15 ns, 50 ohm input pulse	t _{ON+} t _{OFF}		30	ns